Thermodynamics vs. Kinetics

- Thermodynamics:
 - To study the direction of a reaction, or if a reaction can take place. (ΔG <0)
 - To study the equilibrium states in which state variables of a system do not change with time.
- Kinetics:
 - To study the rates and paths of a reaction adopted by the systems approaching equilibrium.
 - To study the rate-limiting steps of a reaction
 - To study the controlling factors of the rate-limiting steps



Thermodynamics vs. Kinetics



Reaction Rate α (Kinetic factor) x (Thermodynamic factor)

- * Kinetic factor relates to Q (activation energy), while the thermodynamic factor relates to the driving force, $\Delta G = G_2 G_1$.
- * The thermodynamic factor decides the direction of a reaction, while the kinetic factor, the rate of reaction.

Kinetic theory: The reaction rate is proportional to the probability to reach activated state that follows the Arrhenius rate equation, exp(-Q/RT).

* The activation energy (Q) can be obtained from the slope of curve plotted as In(reaction rate) vs. 1/T

Example: For diamond growth by CVD from reaction of methane and hydrogen



Kinetic factor increased by changing temperature or adding catalysts.



Progress of Reaction

Examples: (1) $N_2 + 3H_2 = 2NH_3$ using iron as a catalyst (2) $2CO + 2NO = 2CO_2 + N_2$ using Pt and Rh as catalysts for catalytic converters used in automobile

Examples: Thermodynamically favorable but kinetically unfavorable phase changes

(1) Is a diamond forever?



(2) Crystallization of glasses



CaO-SrO-BaO-B $_2O_3$ -SiO $_2$ glass-ceramics annealed at 875°C

Diffusion driven by decrease in chemical potential * Down-hill diffusion



* Up-hill Diffusion



Diffusion:

Process by which matter is transported through matter as a result of molecular motions



General scheme for transport phenomena

Flux α Driving force α Gradient in potentialMatterJ α dC/dx α Heatq α dT/dx α Concentration potential α Temperature potentialElectricityI α $d\phi/dx$ α ElectricityI α $d\phi/dx$ α ElectricityI α $d\phi/dx$ α ElectricityI α $d\phi/dx$ α Electrical potential $J = -D\nabla C$ (Fick's Law)D: diffusivity $q = -k\nabla T$ (Fourier's Law)k: thermal conductivity $I = -\sigma \nabla \phi$ (Ohm's Law) σ : electrical conductivity

Fick's First Law:

Species migrates from a region of high concentration to a region of low concentration ; in general the rate of diffusion is proportional to the concentration gradient

$$J = -D\frac{\partial C}{\partial x}$$

- * Flux (J) : Mass/(area \cdot time), e.g., g/(cm² \cdot sec)
- * Minus (-): Matter moves from high to low concentration.
- * Diffusivity (D): Diffusivity related to atomic mobility and crystal structure, e.g., cm²/sec (independent of concentration gradient)

* Concentration gradient (
$$\frac{\partial C}{\partial x}$$
): Gradient in "Mass Potential,"
e.g., g·cm⁻³/cm



Equilibrium State: No Flux

$$\left(\frac{\partial \mu}{\partial x}\right)_t = 0 = \left(\frac{\partial C}{\partial x}\right)_t$$

Steady State: Constant flux if the area is fixed.

$$\left(\frac{\partial\mu}{\partial t}\right)_x = 0 = \left(\frac{\partial C}{\partial t}\right)_x$$

 μ : Chemical Potential

$$\therefore \Delta \mu = \operatorname{RT} \ln (a) = \operatorname{RT} \ln(\gamma X)$$
$$(\frac{\partial \mu}{\partial x})_{t} = \operatorname{RT} (\frac{\partial \ln(a)}{\partial x})_{t} = \operatorname{RT} (\frac{\partial \ln(\gamma X)}{\partial x})_{t}$$



Fick's Second Law Transient State: C=C(x,t), or J=J(x,t)



Fick's Second Law (cont.)

$$-\frac{\partial C}{\partial t} = \frac{\partial J}{\partial x} = \frac{\partial}{\partial x} \left(-D\frac{\partial C}{\partial x}\right)$$
$$= -D\frac{\partial^2 C}{\partial x^2} - \frac{\partial C}{\partial x}\frac{\partial D}{\partial x}$$
$$= -D\frac{\partial^2 C}{\partial x^2} - \frac{\partial C}{\partial x}\left(\frac{\partial D}{\partial C}\frac{\partial C}{\partial x}\right)$$
$$\oint D \neq D(C)$$
when $D \neq D(C) \rightarrow \frac{\partial D}{\partial C} = 0$
$$\frac{\partial C}{\partial t} = D\frac{\partial^2 C}{\partial x^2} \rightarrow \text{ Fick's Second Law}$$

Linear partial differential equation >Solutions are additive >Solutions require initial and boundary conditions

Transient State:



Transient State -- Thin-film solution (Infinite Sink)

A quantity of solute, S, is plated as a thin film on one end of a long rod of solute-free material, then a similar solute-free rod is welded to the plated end.

Annealed for time $(t) \rightarrow$ Determine concentration profile of the solute.



Transient State -- Thin-film solution (Infinite Sink)

$$C(x,t) = \frac{S'}{2\sqrt{\pi Dt}} \exp(-\frac{x^2}{4Dt})$$



Conservation of mass

$$\int_{-\infty}^{\infty} C(x,t) dx = S'(=2\delta C^*)$$

General Solution:
$$C(x,t) = \frac{A}{\sqrt{t}} \exp(-\frac{x^2}{4Dt})$$
 (A: constant)
Particular Solution: $C(x,t) = \frac{S'}{2\sqrt{\pi Dt}} \exp(-\frac{x^2}{4Dt})$ (Note: $\sqrt{Dt} \gg 2\delta$)
 $\therefore C(0,t) = \frac{S'}{2\sqrt{\pi Dt}}$
 $C(x,t) = C(0,t) \exp(-\frac{x^2}{4Dt})$

Taking the natural logarithm of both sides yields

$$\ln(\frac{C(x,t)}{C(0,t)}) = -\frac{x^2}{4Dt}$$

Thus a graph of $\ln(C(x,t)/C(0,t))$ against x² should yield a straight line with a slope of -1/4Dt.







Sample Dimension



The above analyses are only good for a thin film in the middle of an "**Infinite Bar**". If it is not infinite, the diffusion will be reflected back into the specimen when it reaches the end of the bar, and concentration in that region will be higher than the above solution.

Q: How long is long enough to be considered infinite? Leak Test

Arbitrarily taking 0.1% as a sufficiently insignificant concentration

$$0.1\% = \frac{\int_{l}^{\infty} C(x,t)dx}{\int_{0}^{\infty} C(x,t)dx} = \frac{\int_{l}^{\infty} \frac{S'}{2\sqrt{\pi Dt}} \exp(-\frac{x^{2}}{4Dt})dx}{\int_{0}^{\infty} \frac{S'}{2\sqrt{\pi Dt}} \exp(-\frac{x^{2}}{4Dt})dx} = 10^{-3}$$

Let $u = \frac{x}{2\sqrt{Dt}}, \quad du = \frac{dx}{2\sqrt{Dt}}$
 $x = \infty \quad u = \infty$
 $x = l \quad u = \frac{l}{2\sqrt{Dt}}$

$$10^{-3} = \frac{\frac{S'}{\sqrt{\pi}} \int_{\frac{1}{2\sqrt{Dt}}}^{\infty} \exp(-u^2) du}{\frac{S'}{\sqrt{\pi}} \int_{0}^{\infty} \exp(-u^2) du}$$
$$= \frac{erfc(\frac{l}{2\sqrt{Dt}})}{1} = 1 - erf(\frac{l}{2\sqrt{Dt}})$$
$$\therefore l = 4.6\sqrt{Dt} \quad \text{(Check the Table of Error Function)}$$
$$l \ge 4.6\sqrt{Dt} \quad \text{The bar is considered to be long enoted to be long enoted to use a thin-film solution with 99.9}$$

.ough .9% -TIIM SOLUTION accuracy.

Solution for a pair of Semi-infinite Solids



I.C.
$$C(x,0) = 0$$
 $x < 0$
 $C(x,0) = C'$ $x > 0$
B.C. $C(\infty,t) = C'$
 $C(-\infty,t) = 0$

Superposition

- (1) No interaction from adjacent slabs
- (2) Superposition of the distributions from the individual slabs since the diffusion equation is linear and additive.





$$\alpha = 0 \rightarrow u = \frac{x}{2\sqrt{Dt}}$$
$$\alpha = \infty \rightarrow u = -\infty$$
$$C(x,t) = -\frac{C'}{\sqrt{\pi}} \int_{\frac{x}{2\sqrt{Dt}}}^{-\infty} \exp(-u^2) du$$

reverse limits of integration and split integral

$$C(x,t) = (\int_{-\infty}^{0} + \int_{0}^{\frac{x}{2\sqrt{Dt}}}) \frac{C'}{\sqrt{\pi}} \exp(-u^{2}) du$$

By definition of error function

$$erf(z) = \frac{2}{\sqrt{\pi}} \int_0^z \exp(-u^2) du$$

$$erf(\infty) = 1 \quad erf(0) = 0$$

$$erf(-z) = -erf(z)$$

$$C(x,t) = \frac{C}{\sqrt{\pi}} [\int_{-\infty}^0 \exp(-u^2) du + \int_0^{\frac{x}{2\sqrt{Dt}}} \exp(-u^2) du]$$

$$= \frac{C}{\sqrt{\pi}} [\frac{\sqrt{\pi}}{2} + \frac{\sqrt{\pi}}{2} erf(\frac{x}{2\sqrt{Dt}})]$$

$$= \frac{C}{2} [1 + erf(\frac{x}{2\sqrt{Dt}})]$$



Note:

If the concentration is fixed (C=C*), the term of $x/2\sqrt{Dt}$ is then also fixed. This means that the penetration distance is a function of the square root of the diffusion time. For example, if a diffusion penetration of 0.1mm develops in one hour, it will take 4 hours to develop a penetration of 0.2 mm.

$$\frac{C}{C_0} = \frac{1}{2} \left[1 + erf\left(\frac{x}{2\sqrt{Dt}}\right) \right]$$
(1) $x > 0$ $\frac{C}{C_0} = 0.5 + \frac{1}{2} erf\left(\frac{x}{2\sqrt{Dt}}\right)$
 $x < 0$ $\frac{C}{C_0} = 0.5 - \frac{1}{2} erf\left(\frac{|x|}{2\sqrt{Dt}}\right)$
(2) $\frac{x}{2\sqrt{Dt}} = 1 \rightarrow \frac{C}{C_0} = 0.921$
which varies with time as $x = 2\sqrt{Dt}$
(all compositions except $\frac{C}{C_0} = 0.5$).
(3) $x = 0 \rightarrow \frac{C}{C_0} = \frac{1}{2}$ (implicit B.C.)
(4) $J_{x=0} = -D\frac{\partial C}{\partial x}|_{x=0} = -\frac{C_0}{2}\sqrt{\frac{D}{\pi t}}$ (-:to the left)
(5) Total mass crosses the plane at $x = 0$
 $\frac{M}{A} = \int_0^t Jdt = -C_0\sqrt{\frac{Dt}{\pi}}$ (A:area)

The above analyses are only good for an "<u>Infinite Slab</u>". If it is not infinite, the diffusion will be reflected back into the specimen when it reaches the end of the bar, and concentration in that region will be higher than the above solution.

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Using B.C. to solve the problem $C(x,t) = A + B \cdot erf\left(\frac{x}{2\sqrt{Dt}}\right)$ $C(\infty, t) = C' = A + B$ $C(-\infty,t) = 0 = A - B \implies A = B = \frac{C'}{2}$ ~1

$$C(x,t) = \frac{C}{2} \left[1 + erf\left(\frac{x}{2\sqrt{Dt}}\right)\right]$$

Examples (1) if C(0, t) = 0 $C(x,t) = C'erf(\frac{x}{2\sqrt{Dt}})$ (2) if C(0, t) = C'' = A, $C(\infty, t) = C'$ $C(x,t) = C''[1 + erf(\frac{x}{2\sqrt{Dt}})], \quad x < 0$ $\frac{C-C''}{C'-C''} = erf(\frac{x}{2\sqrt{Dt}}), \qquad x > 0$ (next page)



Diffusion from a Limited Source (thin film)



 $C(0,t) \neq \text{constant}$ $\int_0^\infty C(x,t)dx = S_0 \to \text{constant}$ $C(x,t) = \frac{S_0}{\sqrt{\pi Dt}} \exp(-\frac{x^2}{4Dt})$:Gaussian function Example: p-n junction C = Background Concentration C > C' $(p \rightarrow n \text{ or } n \rightarrow p)$ $C' = \frac{S_0}{\sqrt{\pi Dt}} \exp(-\frac{{x_j}^2}{4Dt})$ x_i = junction distance

Diffusion from a Constant Source



$$C(0,t) = C_0$$

$$C(x,t) = C_0 \operatorname{erfc}\left(\frac{x}{2\sqrt{Dt}}\right)$$

$$M = A \cdot \int_0^\infty C(x,t) dx = 2AC_0 \sqrt{\frac{Dt}{\pi}}$$

: the amount of dopant entering the base

Example: p-n junction C'= Background Concentration $C > C' \quad (p \to n \text{ or } n \to p)$ $C' = C_0 \operatorname{erfc}(\frac{x_j}{2\sqrt{Dt}})$

 x_i : junction distance

Separation of Variables



 $\diamond \text{Series Solutions}$

 \diamond Small system + long time

Assuming the solution can be represented by

$$C(x,t) = X(x)T(t)$$

$$\frac{\partial C}{\partial t} = D \frac{\partial^2 C}{\partial x^2} \text{ assuming } D \neq D(C)$$

$$X \frac{dT}{dt} = DT \frac{\partial^2 X}{\partial x^2}$$

$$X(x)T'(t) = DTX "$$

Divide both sides by C(x,t)

$$\frac{X\frac{dT}{dt}}{XT} = \frac{DTX''}{XT}$$
$$\frac{T'}{DT} = \frac{X''}{X}$$
$$\frac{T'}{DT} : \text{function only of time}$$
$$\frac{X''}{X} : \text{function only of distance}$$

Since they vary independently, both sides must be equal to a constant, designated as – λ^2 where λ is a real number

$$\frac{1}{T}\frac{dT}{dt} = -\lambda^2 D$$
$$T = T_0 \exp(-\lambda^2 Dt)$$

where T_0 is a constant, – λ^2 is chosen because one deals with the system in which any inhomogeneities disappear as time passes, i.e., T approaches zero as time increases. The equation in \boldsymbol{X} is

$$\frac{d^2 X}{dx} + \lambda^2 X = 0$$

the solution to this equation is of the form

 $X(x) = A' \sin(\lambda x) + B' \cos(\lambda x)$

where A' and B' are functions of λ C(x,t) = X(x)T(t) $= T_0 \exp(-\lambda^2 Dt)(A' \sin \lambda x + B' \cos \lambda x)$ $= (A \sin \lambda x + B \cos \lambda x) \exp(-\lambda^2 Dt)$

But if this solution holds for any real value of λ , then a sum of solutions with different values of λ is also a solution. Thus in its most general form the product solution will be infinite series of the form

$$C(x,t) = \sum_{n=1}^{\infty} \left[(A_n \sin \lambda_n x + B_n \cos \lambda_n x) \exp(-\lambda_n^2 Dt) \right]$$



Multiplying both sides by $\sin(\frac{p\pi x}{h})$ and integrate x over the range of $0 \le x \le h$ to determine A_n

$$\int_{0}^{h} C_{0} \sin(\frac{p\pi x}{h}) dx = \sum_{n=1}^{\infty} A_{n} \int_{0}^{h} \sin(\frac{n\pi x}{h}) \sin(\frac{p\pi x}{h}) dx$$
$$n \neq p \rightarrow \sum_{n=1}^{\infty} A_{n} \int_{0}^{h} \sin(\frac{n\pi x}{h}) \sin(\frac{p\pi x}{h}) dx = 0$$
$$n = p \rightarrow \sum_{n=1}^{\infty} A_{n} \int_{0}^{h} \sin(\frac{n\pi x}{h}) \sin(\frac{p\pi x}{h}) dx = \frac{h}{2} A_{n}$$

$$A_{n} = \frac{2}{h} \int_{0}^{h} C_{0} \sin(\frac{n\pi x}{h}) dx = \frac{2C_{0}}{h} (-\frac{h}{n\pi}) \cos(\frac{n\pi x}{h}) \Big|_{0}^{h} = \frac{2C_{0}}{n\pi} \cos(\frac{n\pi x}{h}) \Big|_{h}^{0}$$
$$= \frac{2C_{0}}{n\pi} [\cos(\frac{n\pi 0}{h}) - \cos(\frac{n\pi h}{h})] = \frac{2C_{0}}{n\pi} [1 - \cos(n\pi)]$$
$$n : even \to A_{n} = 0$$
$$n : odd = 2j + 1 \to A_{n} = \frac{4C_{0}}{n\pi} = \frac{4C_{0}}{(2j+1)\pi} \quad j = 0, 1, 2....$$
The solution is $C(x,t) = \frac{4C_{0}}{\pi} \sum_{j=0}^{\infty} \frac{1}{(2j+1)} \sin(\frac{(2j+1)\pi x}{h}) \exp(-(\frac{(2j+1)\pi}{h})^{2})$

Note: Each successive term is smaller than the preceding one, and the percentage decreases between terms and increases exponentially with time. Thus after a short time has elapsed, the infinite series can be satisfactorily represented by only a few terms. To determine the error, we compare the ratio of the maximum values of the first and second terms (R) $8\pi^2 Dt$

Dt)

$$R = 3\exp(\frac{8\pi Dt}{h^2})$$

$$R = 100$$
 when $h = 4.75\sqrt{Dt}$

$$t \ge \frac{h^2}{\left(4.75\right)^2 D}$$

The error in using the first term to represent C(x,t) is less than 1% at all points.

Degassing of Metals

It is difficult to measure the concentration of gas at various depths, and what is experimentally determined is the quantity of gas which has been given off or the quantity remaining in the metal. Therefore, the average concentration (C) is used.

$$\overline{C} = \frac{1}{h} \int_0^h C(x,t) dx$$

= $\frac{8C_0}{\pi^2} \sum_{j=0}^\infty \frac{1}{(2j+1)^2} \exp(-(\frac{(2j+1)\pi}{h})^2 Dt)$

When $\overline{C}(t) \le 0.8C_0$ the first term is a good approximation to the solution or when t is sufficiently large



Solutions for Variable D

$$\frac{\partial C}{\partial t} = \frac{\partial}{\partial x} \left(D \frac{\partial C}{\partial x} \right) = \frac{\partial D}{\partial x} \frac{\partial C}{\partial x} + D \frac{\partial^2 C}{\partial x^2}$$

 $\frac{\partial D}{\partial x}$ makes this equation inhomogeneous, especially when D=D(C) or D(T) or D(t) or D(x). The key in solving the above p.d.e. is to simplify the equation with x and t to x or t function.

Boltzman-Matano Analysis (D=D(C))

 $\eta = \frac{x}{\sqrt{t}}$ $\frac{\partial C}{\partial t} = \frac{\partial C}{\partial \eta} \frac{\partial \eta}{\partial t} = -\frac{1}{2} \frac{x}{t^{3/2}} \frac{\partial C}{\partial \eta}$ and $\frac{\partial C}{\partial x} = \frac{\partial C}{\partial \eta} \frac{\partial \eta}{\partial x} = \frac{1}{\sqrt{t}} \frac{\partial C}{\partial \eta}$ Therefore $-\frac{1}{2}\frac{x}{t^{3/2}}\frac{\partial C}{\partial \eta} = \frac{\partial}{\partial x}(\frac{D}{\sqrt{t}}\frac{\partial C}{\partial \eta})$ $=\frac{1}{t}\frac{\partial}{\partial n}(D\frac{\partial C}{\partial n})$ $-\frac{\eta}{2}\frac{\partial C}{\partial n} = \frac{\partial}{\partial n}(D\frac{\partial C}{\partial n})$



I.C.
$$C(x,0)=Co \quad x<0 \rightarrow \eta = -\infty$$

 $C(x,0)=0 \quad x>0 \rightarrow \eta = \infty$

* x=0 is not determined yet

If $D \neq D(C)$, $C=C_o/2$ which determines x=0 for an infinite system. However, if D=D(C) the above condition is no longer valid, the x=0 must be determined by

$$\int_0^{C_0} x dC = 0$$

which expresses the equality of the two shaded areas.



For an infinite system

 $\frac{dC}{dx} = 0 \quad when \quad C = 0 \quad or \quad C = C_o \quad \therefore \frac{dC}{dx} \Big|_0^{C_0} = 0$

Therefore

$-\frac{1}{2}\int_0^{C_0} xdC = h$	$Dt \frac{dC}{dx}\Big _0^{C_0}$
$\because \frac{dC}{dx} \Big _0^{C_0} = 0$	٥L
$\therefore \int_0^{C_0} x dC = 0$	which is an additional boundary condition and determines the location of Matano interface.

x=0 plane (Matano interface) determined by

$$\int_{0}^{C_{0}} x dC = 0$$

$$D(C') = \frac{-1}{2t} \left(\frac{dx}{dC}\right)_{C'} \int_{0}^{C'} x dC$$





The Moving Boundary Problem

*Diffusion controlling process along with reaction at phase boundary



* $C_{\rm I}^*$ and C_{II}^* : equilibrium concentrations in phases I and II.

*
$$x > S$$
 $\frac{\partial C_{\mathrm{I}}}{\partial t} = D_{\mathrm{I}} \frac{\partial^2 C_{\mathrm{I}}}{\partial x^2}$
 $x < S$ $\frac{\partial C_{\mathrm{II}}}{\partial t} = D_{\mathrm{II}} \frac{\partial^2 C_{\mathrm{II}}}{\partial x^2}$

* Diffusion controlling process

$$C_{I}^{*} = kC_{II}^{*}$$

k: partition ratio between phases

*
$$D_{\mathrm{I}} \left(\frac{\partial C_{\mathrm{I}}}{\partial x}\right)_{x=S} - D_{\mathrm{II}} \left(\frac{\partial C_{\mathrm{II}}}{\partial x}\right)_{x=S} = \left(C_{\mathrm{II}}^* - C_{\mathrm{I}}^*\right) \frac{dS}{dt}$$

Kinetic Issue
$$\frac{dS}{dt} = ?$$

Decarburization



To have net diffusion flux between α and $\gamma,$ the thickness of α + γ has to





Mass Conservation



A: area for diffusion: constant

Carburization



Example: Carburization

*Chemical activity of carbon at surface can be set up by

$$2CO \xleftarrow{k} C + CO_{2}$$

$$a_{c} = \frac{k[CO]^{2}}{[CO_{2}]}; \text{ or}$$

$$CH_{4} \xleftarrow{k} 2H_{2} + C$$

$$a_{c} = \frac{k[CH_{4}]}{P_{H_{2}}^{2}}$$

*Rate of advance of boundary controlled by diffusion of carbon in Fe. Therefore

 $x = S \quad C_{\gamma}^{*} = kC_{\alpha}^{*}$ (if $C_{\gamma}^{*} = C_{\alpha}^{*}$ at $x = S \Rightarrow$ reaction controlling process) $C = C_{\gamma}^{*}$ at $x = S^{-}$ $C = C_{\alpha}^{*}$ at $x = S^{+}$

* Semi-infinite solid

 $\bigstar \qquad D_C \neq D(C) \quad D_\alpha^C \neq D_\gamma^C$

 $\Delta V_{\alpha \rightarrow \gamma} = 0$ mass flux requiring no density correction

*

*



 $\frac{\partial C_{\gamma}}{\partial t} = D_{\gamma}^{C} \frac{\partial^{2} C_{\gamma}}{\partial x^{2}} \quad 0 < x < S$ *I.C.*: $C(x,0) = C_0$ B.C.: in α phase $C = C_{\alpha}^*$ at $x = S^+$ $C = C_0$ at $x = \infty$ in γ phase **x** $C = C_{\gamma}^*$ at $x = S^ C = C_s$ at x = 0 $C(s,t) = C_{\gamma}^* = kC_{\alpha}^*$ (k: Partition Ratio) $(J_{\gamma} - J_{\alpha})dt = (C_{\gamma}^* - C_{\alpha}^*)dS$ $-D_{\gamma}^{C}\left(\frac{\partial C_{\gamma}}{\partial r}\right)_{x=s} + D_{\alpha}^{C}\left(\frac{\partial C_{\alpha}}{\partial r}\right)_{x=s} = \left(C_{\gamma}^{*} - C_{\alpha}^{*}\right)\frac{dS}{dt}$ Note: $(J_{\gamma} - J_{\alpha})dt \cdot A = (C_{\gamma}^* - C_{\alpha}^*)dS \cdot A$

In α phase

$$C_{\alpha} = A + B \cdot erfc(\frac{x}{2\sqrt{D_{\alpha}^{C}t}}), \quad x = \infty \rightarrow C_{\alpha} = C_{0} = A$$

In γ phase



Similarly

$$C_{\alpha}(S,t) = C_{\alpha}^{*} = C_{0} + B \cdot erfc(\frac{S}{2\sqrt{D_{\alpha}^{C}t}}) = C_{0} + B \cdot erfc(\frac{2\beta\sqrt{D_{\gamma}^{C}t}}{2\sqrt{D_{\alpha}^{C}t}})$$
Replace $\phi = \frac{D_{\gamma}^{C}}{D_{\alpha}^{C}}$

$$C_{\alpha}(S,t) = C_{0} + B \cdot erfc(\beta\phi^{\frac{1}{2}}) = C_{\alpha}^{*}$$

$$-D_{\gamma}^{C}(\frac{\partial C_{\gamma}}{\partial x})_{x=s} = \frac{-D_{\gamma}^{C}B'}{2\sqrt{D_{\gamma}^{C}t}}\frac{2}{\sqrt{\pi}}\exp(-\frac{x^{2}}{4D_{\gamma}^{C}t})|_{x=s}$$
(1)
$$D_{\alpha}^{C}(\frac{\partial C_{\alpha}}{\partial x})_{x=s} = \frac{-D_{\alpha}^{C}B}{2\sqrt{D_{\alpha}^{C}t}}\frac{2}{\sqrt{\pi}}\exp(-\frac{x^{2}}{4D_{\alpha}^{C}t})|_{x=s}$$
(2)
$$Eq.(1) + (2) = (C_{\gamma}^{*} - C_{\alpha}^{*})(\frac{\partial S}{\partial t})$$

$$S = 2\beta\sqrt{D_{\gamma}^{C}t}$$

$$\therefore \frac{dS}{dt} = \beta\sqrt{\frac{D_{\gamma}^{C}}{t}}$$
 (Note: it is not a constant)
$$C_{\gamma}^{*} - C_{\alpha}^{*} = \frac{-B^{*}e^{-\beta^{2}}}{\sqrt{\pi\beta}} - \frac{Be^{-\beta^{2}\phi}}{\sqrt{\pi\beta}\sqrt{\phi}}$$



Note: the only unknown parameter in the above equation is β $(C_{\gamma}^*, C_{\alpha}^*, C_s, C_0, D_{\gamma}^C \text{ and } D_{\alpha}^C \text{ are known parameters})$

Example: Decarburization 0.4% Carbon Alloy Steel T=800°C $C_s=0.01\%$ (equilibrium by CO and CO_2) t = 30 min \rightarrow S_{*a*-Fe}? Answer: $C_0 = 0.4\%$, $C_s = 0.01\%$ C_{y} *=0.24%, C_{a} *=0.02% (Obtained from Fe-C Phase Diagram) $D_{\alpha}^{C} = 3 \times 10^{-8}; \quad D_{\nu}^{C} = 2 \times 10^{-6} \quad \text{cm}^{2}/\text{sec}$ $\phi = \frac{D_{\gamma}^{c}}{D^{c}} = 66.6$ $(C_{\alpha}^{*} - C_{\gamma}^{*}) = \frac{C_{s} - C_{\alpha}^{*}}{\sqrt{\pi} \beta e^{\beta^{2}} erf(\beta)} - \frac{C_{\gamma} - C_{0}}{\sqrt{\pi} \beta \phi^{\frac{1}{2}} e^{\beta^{2} \phi} erfc(\beta \phi^{\frac{1}{2}})}$ $(0.02 - 0.24) = \frac{(0.01 - 0.02)}{f(\beta)} - \frac{(0.24 - 0.4)}{f(\beta\phi^{1/2})}$ $0.22 = \frac{0.01}{f(\beta)} - \frac{(0.24 - 0.4)}{f(\beta \phi^{1/2})}$ by trial and error $\Rightarrow \beta = 0.144$ (see Figure) $S = 2\beta \sqrt{D_{\nu}^{C}t} = 0.0173 \ cm$

Formation of a single-phase layer from an initial two-phase mixture

In the two-phase region, the average composition, C_o , is assumed to be uniform, which requires, in effect, that the grain size is small and that second-phase dispersion is uniform.

